DESCRIPTION

The SPN3402 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits, and low in-line power loss are needed in a very small outline surface mount package.

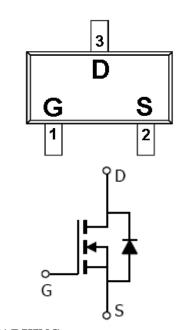
APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

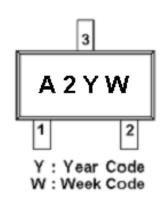
FEATURES

- 30V/2.8A, RDS(ON)= $58m\Omega$ @VGS=10V
- 30V/2.3A,RDS(ON)= $65m\Omega$ @VGS=4.5V
- 30V/1.5A,RDS(ON)= $105m\Omega$ @VGS=2.5V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ◆ SOT-23-3L package design

PIN CONFIGURATION (SOT-23-3L)



PART MARKING



PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN3402S23RGB	SOT-23-3L	A2

% Week Code : A ~ Z(1 ~ 26); a ~ z(27 ~ 52)

※ SPN3402S23RGB : Tape Reel ; Pb − Free; Halogen - Free

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

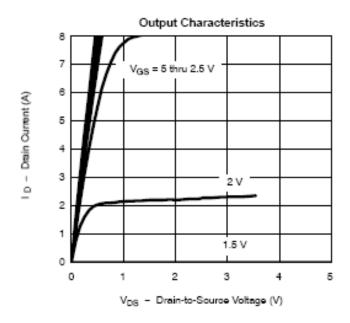
Parameter		Symbol	Typical	Unit
Drain-Source Voltage		Vdss	30	V
Gate –Source Voltage		VGSS	±12	V
Continue Dair Connect(To 1500C)	Ta=25°C	- ID	4.0	
Continuous Drain Current(T _J =150°C)	Ta=70°C		2.8	A
Pulsed Drain Current		Ірм	10	A
Continuous Source Current(Diode Conduction)		Is	1.25	A
D D' :	Ta=25°C	D-	1.25	***
Power Dissipation	Ta=70°C	PD	0.8	W
Operating Junction Temperature		τJ	150	°C
Storage Temperature Range		Tstg	-55/150	°C
Thermal Resistance-Junction to Ambient		R _θ JA	100	°C/W

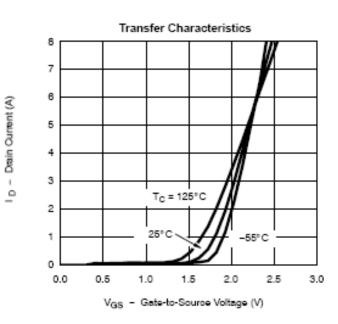
ELECTRICAL CHARACTERISTICS

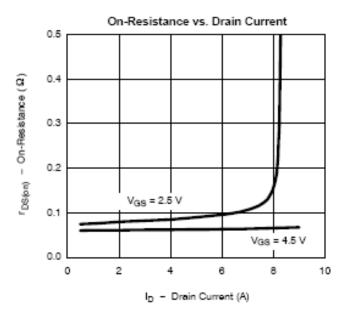
(TA=25°C Unless otherwise noted)

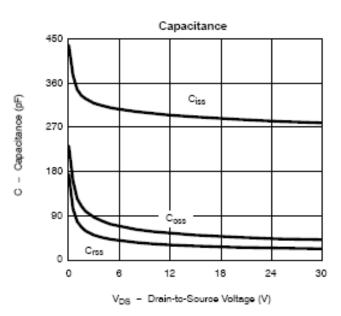
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	30			V	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.5		1.6	V	
Gate Leakage Current	Igss	V _{DS} =0V,V _{GS} =±12V			±100	nA	
Zero Gate Voltage Drain Current		VDS=24V,VGS=0.0V			1	uA	
	Idss	V _{DS} =24V,V _{GS} =0.0V T _J =55°C			10		
On-State Drain Current	ID(on)	V _{DS} ≥ 4.5V, V _{GS} =10V	6			A	
	ID(on)	$V_{DS} \ge 4.5V, V_{GS} = 4.5V$	4				
		$V_{GS} = 10V, I_{D}=2.8A$		0.048	0.058	Ω	
Drain-Source On-Resistance	RDS(on)	VGS =4.5V,ID=2.3A		0.053	0.065		
T. 1.00	6	VGS =2.5V,ID=1.5A		0.080	0.105	-	
Forward Transconductance	gfs	VDS=4.5V,ID=2.8A		4.6		S	
Diode Forward Voltage	Vsd	Is=1.25A,VGS=0V		0.82	1.2	V	
Dynamic							
Total Gate Charge	Qg			4.2	6	nC	
Gate-Source Charge	Qgs	VDS=15,VGS=4.5V ID=2.0A		0.6			
Gate-Drain Charge	Qgd	-ID-2.0A		1.5			
Input Capacitance	Ciss			350		pF	
Output Capacitance	Coss	V _{DS} =15,V _{GS} =0V f =1MHz		55			
Reverse Transfer Capacitance	Crss			41			
Turn-On Time	td(on)			2.5		nS	
	tr	$V_{DD}=15,RL=10\Omega$		2.5			
	td(off)	$V_{GEN}=10V,R_{G}=3\Omega$		20			
Turn-Off Time	tf	1		4			

TYPICAL CHARACTERISTICS

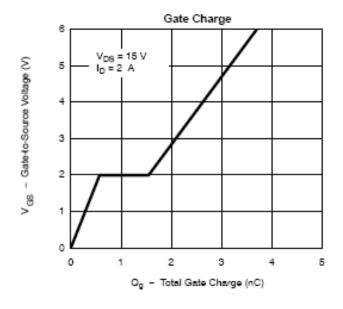


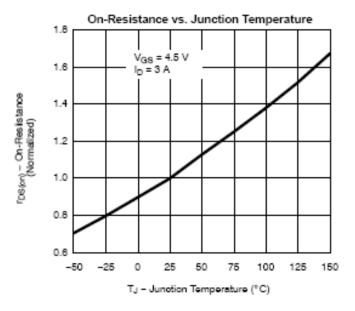


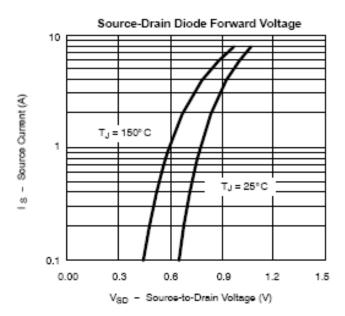


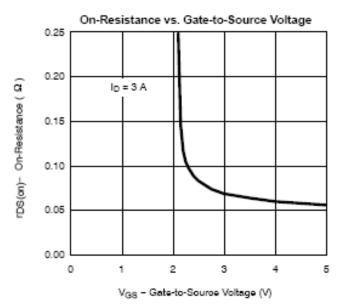


TYPICAL CHARACTERISTICS

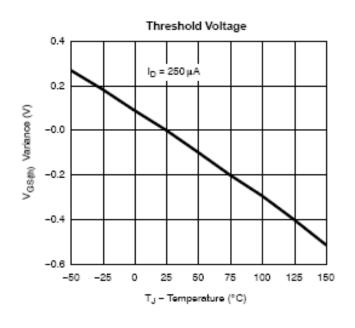


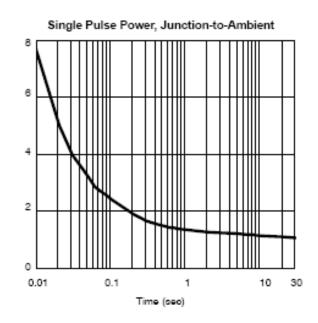


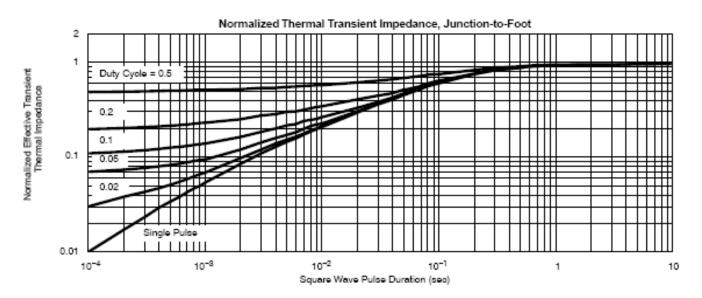




TYPICAL CHARACTERISTICS







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